

**DS90CR285/DS90CR286 +3.3V Rising Edge Data Strobe LVDS 28-Bit Channel Link-66 MHz**Check for Samples: [DS90CR285](#), [DS90CR286](#)**FEATURES**

- **Single +3.3V Supply**
- **Chipset (Tx + Rx) Power Consumption <250 mW (typ)**
- **Power-Down Mode (<0.5 mW total)**
- **Up to 231 Megabytes/sec Bandwidth**
- **Up to 1.848 Gbps Data Throughput**
- **Narrow Bus Reduces Cable Size**
- **290 mV Swing LVDS Devices for Low EMI**
- **+1V Common Mode Range (Around +1.2V)**
- **PLL Requires no External Components**
- **Both Devices are Offered in a Low Profile 56-Lead TSSOP Package**
- **Rising Edge Data Strobe**
- **Compatible with TIA/EIA-644 LVDS Standard**
- **ESD Rating > 7 kV**
- **Operating Temperature: –40°C to +85°C**

**DESCRIPTION**

The DS90CR285 transmitter converts 28 bits of LVCMOS/LVTTL data into four LVDS (Low Voltage Differential Signaling) data streams. A phase-locked transmit clock is transmitted in parallel with the data streams over a fifth LVDS link. Every cycle of the transmit clock 28 bits of input data are sampled and transmitted. The DS90CR286 receiver converts the LVDS data streams back into 28 bits of LVCMOS/LVTTL data. At a transmit clock frequency of 66 MHz, 28 bits of TTL data are transmitted at a rate of 462 Mbps per LVDS data channel. Using a 66 MHz clock, the data throughput is 1.848 Gbit/s (231 Mbytes/s).

The multiplexing of the data lines provides a substantial cable reduction. Long distance parallel single-ended buses typically require a ground wire per active signal (and have very limited noise rejection capability). Thus, for a 28-bit wide data and one clock, up to 58 conductors are required. With the Channel Link chipset as few as 11 conductors (4 data pairs, 1 clock pair and a minimum of one ground) are needed. This provides a 80% reduction in required cable width, which provides a system cost savings, reduces connector physical size and cost, and reduces shielding requirements due to the cables' smaller form factor.

The 28 LVCMOS/LVTTL inputs can support a variety of signal combinations. For example, seven 4-bit nibbles or three 9-bit (byte + parity) and 1 control.



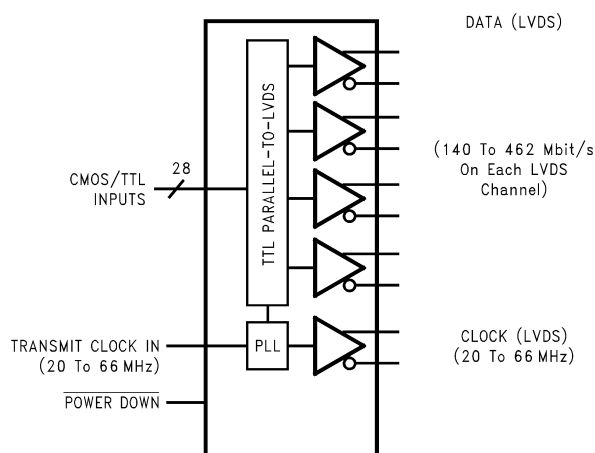
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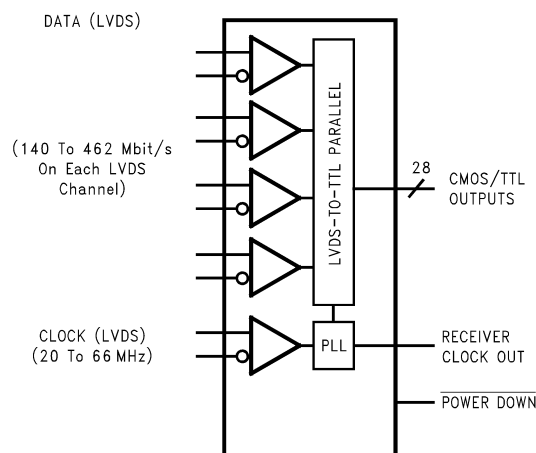
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## Block Diagram

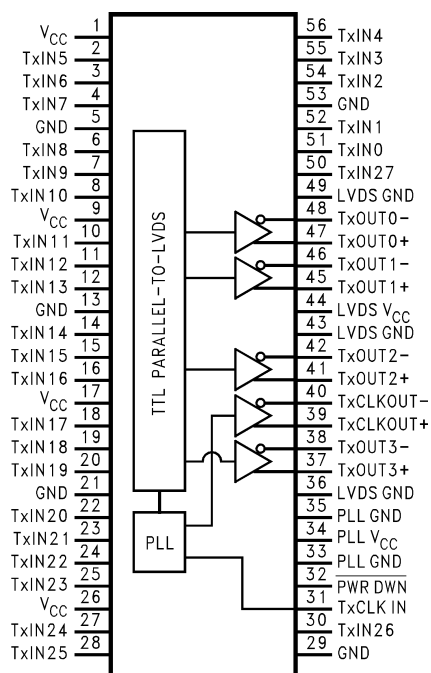


**Figure 1. DS90CR285 - 56-Lead TSSOP**  
See Package Number DGG0056A

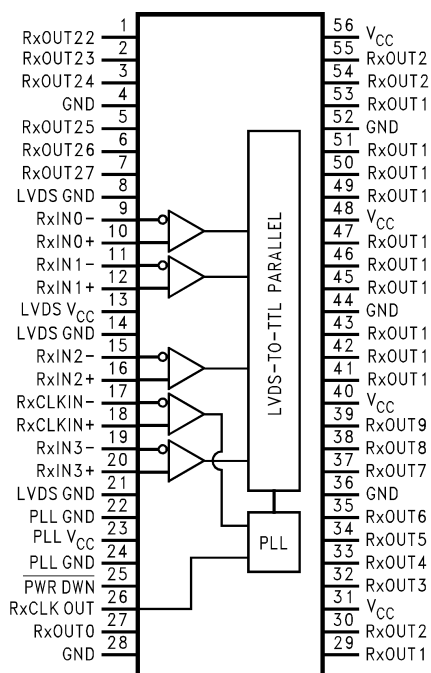


**Figure 2. DS90CR285 - 56-Lead TSSOP**  
See Package Number DGG0056A

## Pin Diagrams for TSSOP Packages

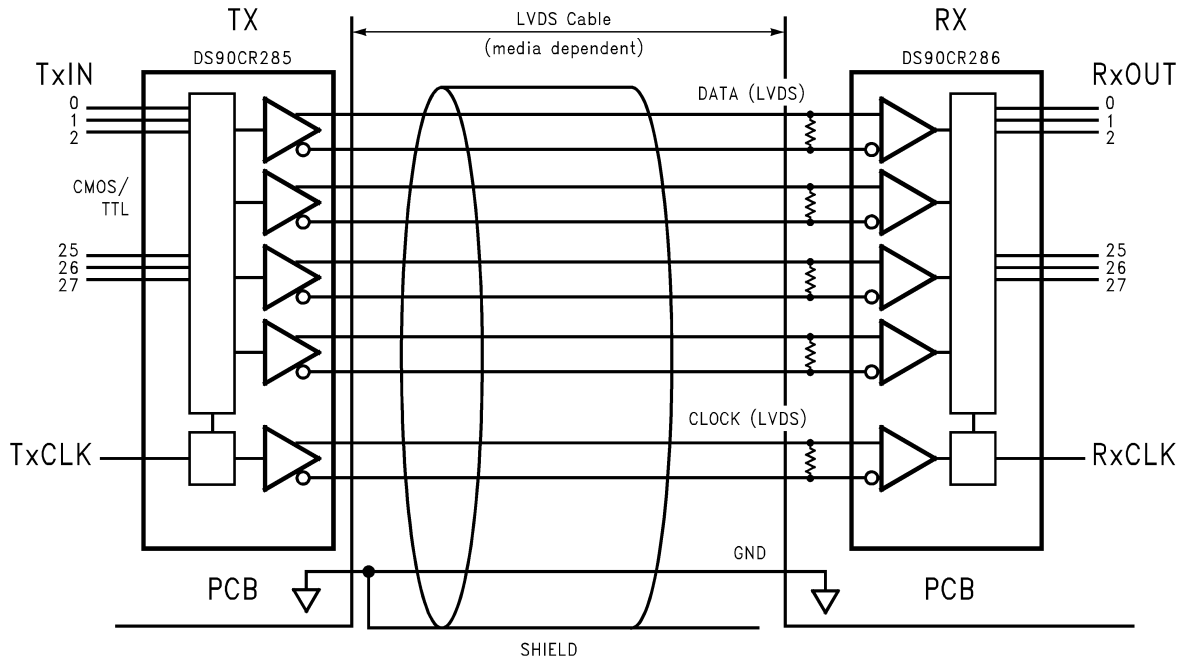


**Figure 3. DS90CR285**  
See Package Number DGG (R-PDSO-G56)



**Figure 4. DS90CR286**  
See Package Number DGG (R-PDSO-G56)

## Typical Application



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## Absolute Maximum Ratings <sup>(1)(2)</sup>

Supply Voltage (V <sub>CC</sub> )			-0.3V to +4V
CMOS/TTL Input Voltage			-0.3V to (V <sub>CC</sub> + 0.3V)
CMOS/TTL Output Voltage			-0.3V to (V <sub>CC</sub> + 0.3V)
LVDS Receiver Input Voltage			-0.3V to (V <sub>CC</sub> + 0.3V)
LVDS Driver Output Voltage			-0.3V to (V <sub>CC</sub> + 0.3V)
LVDS Output Short Circuit Duration			Continuous
Junction Temperature			+150°C
Storage Temperature			-65°C to +150°C
Lead Temperature (Soldering, 4 sec.)			+260°C
Solder Reflow Temperature	Maximum Package Power Dissipation @ +25°C	DS90CR285MTD	1.63 W
		DS90CR286MTD	1.61 W
	Package Derating:	DS90CR285MTD	12.5 mW/°C above +25°C
		DS90CR286MTD	12.4 mW/°C above +25°C
ESD Rating (HBM, 1.5 kΩ, 100 pF)			> 7 kV

- (1) "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the device should be operated at these limits. "Electrical Characteristics" specify conditions for device operation.
- (2) If Military/Aerospace specified devices are required, please contact the TI Sales Office/ Distributors for availability and specifications.

## Recommended Operating Conditions

	Min	Nom	Max	Units
Supply Voltage ( $V_{CC}$ )	3.0	3.3	3.6	V
Operating Free Air Temperature ( $T_A$ )	-40	+25	+85	°C
Receiver Input Range	0			V
Supply Noise Voltage ( $V_{CC}$ )				100 mV <sub>PP</sub>

## Electrical Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Unit s	
LVCMOS/LVTTL DC SPECIFICATIONS							
V <sub>IH</sub>	High Level Input Voltage		2.0		V <sub>CC</sub>	V	
V <sub>IL</sub>	Low Level Input Voltage		GND		0.8	V	
V <sub>OH</sub>	High Level Output Voltage	I <sub>OH</sub> = -0.4 mA	2.7	3.3		V	
V <sub>OL</sub>	Low Level Output Voltage	I <sub>OL</sub> = 2 mA		0.06	0.3	V	
V <sub>CL</sub>	Input Clamp Voltage	I <sub>CL</sub> = -18 mA		-0.79	-1.5	V	
I <sub>IN</sub>	Input Current	V <sub>IN</sub> = V <sub>CC</sub> , GND, 2.5V or 0.4V		±5.1	±10	µA	
I <sub>OS</sub>	Output Short Circuit Current	V <sub>OUT</sub> = 0V		-60	-120	mA	
LVDS DRIVER DC SPECIFICATIONS							
V <sub>OD</sub>	Differential Output Voltage	R <sub>L</sub> = 100Ω	250	290	450	mV	
ΔV <sub>OD</sub>	Change in V <sub>OD</sub> between Complimentary Output States				35	mV	
V <sub>OS</sub>	Offset Voltage <sup>(1)</sup>		1.125	1.25	1.375	V	
ΔV <sub>OS</sub>	Change in V <sub>OS</sub> between Complimentary Output States				35	mV	
I <sub>OS</sub>	Output Short Circuit Current	V <sub>OUT</sub> = 0V, R <sub>L</sub> = 100Ω		-3.5	-5	mA	
I <sub>OZ</sub>	Output TRI-STATE Current	PWR DWN = 0V, V <sub>OUT</sub> = 0V or V <sub>CC</sub>		±1	±10	µA	
LVDS RECEIVER DC SPECIFICATIONS							
V <sub>TH</sub>	Differential Input High Threshold	V <sub>CM</sub> = +1.2V			+100	mV	
V <sub>TL</sub>	Differential Input Low Threshold		-100			mV	
I <sub>IN</sub>	Input Current	V <sub>IN</sub> = +2.4V, V <sub>CC</sub> = 3.6V			±10	µA	
		V <sub>IN</sub> = 0V, V <sub>CC</sub> = 3.6V			±10	µA	
TRANSMITTER SUPPLY CURRENT							
I <sub>CCTW</sub>	Transmitter Supply Current Worst Case (with Loads)	R <sub>L</sub> = 100Ω, C <sub>L</sub> = 5 pF, Worst Case Pattern (Figure 5 Figure 6) , T <sub>A</sub> = -10°C to +70°C	f = 32.5 MHz		31	45	mA
			f = 37.5 MHz		32	50	mA
			f = 66 MHz		37	55	mA
		R <sub>L</sub> = 100Ω, C <sub>L</sub> = 5 pF, Worst Case Pattern (Figure 5 Figure 6) , T <sub>A</sub> = -40°C to +85°C	f = 40 MHz		38	51	mA
			f = 66 MHz		42	55	mA
I <sub>CCTZ</sub>	Transmitter Supply Current Power Down	PWR DWN = Low Driver Outputs in TRI-STATE under Powerdown Mode		10	55	µA	
RECEIVER SUPPLY CURRENT							
I <sub>CCRW</sub>	Receiver Supply Current Worst Case	C <sub>L</sub> = 8 pF, Worst Case Pattern (Figure 5 Figure 7) , T <sub>A</sub> = -10°C to +70°C	f = 32.5 MHz		49	65	mA
			f = 37.5 MHz		53	70	mA
			f = 66 MHz		78	105	mA
		C <sub>L</sub> = 8 pF, Worst Case Pattern (Figure 5 Figure 7) , T <sub>A</sub> = -40°C to +85°C	f = 40 MHz		55	82	mA
			f = 66 MHz		78	105	mA
I <sub>CCRZ</sub>	Receiver Supply Current Power Down	PWR DWN = Low Receiver Outputs Stay Low during Powerdown Mode		10	55	µA	

(1)  $V_{OS}$  previously referred as  $V_{CM}$ .

## Transmitter Switching Characteristics

Over recommended operating supply and  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  ranges unless otherwise specified

Symbol	Parameter		Min	Typ	Max	Units
LLHT	LVDS Low-to-High Transition Time (Figure 6)			0.5	1.5	ns
LHLT	LVDS High-to-Low Transition Time (Figure 6)			0.5	1.5	ns
TCIT	TxCLK IN Transition Time (Figure 8)				5	ns
TCCS	TxOUT Channel-to-Channel Skew (Figure 9)			250		ps
TPPos0	Transmitter Output Pulse Position for Bit0 ( <sup>(1)</sup> Figure 20)	f = 40 MHz	–0.4	0	0.4	ns
TPPos1	Transmitter Output Pulse Position for Bit1		3.1	3.3	4.0	ns
TPPos2	Transmitter Output Pulse Position for Bit2		6.5	6.8	7.6	ns
TPPos3	Transmitter Output Pulse Position for Bit3		10.2	10.4	11.0	ns
TPPos4	Transmitter Output Pulse Position for Bit4		13.7	13.9	14.6	ns
TPPos5	Transmitter Output Pulse Position for Bit5		17.3	17.6	18.2	ns
TPPos6	Transmitter Output Pulse Position for Bit6		21.0	21.2	21.8	ns
TPPos0	Transmitter Output Pulse Position for Bit0 ( <sup>(2)</sup> Figure 20)	f = 66 MHz	–0.4	0	0.3	ns
TPPos1	Transmitter Output Pulse Position for Bit1		1.8	2.2	2.5	ns
TPPos2	Transmitter Output Pulse Position for Bit2		4.0	4.4	4.7	ns
TPPos3	Transmitter Output Pulse Position for Bit3		6.2	6.6	6.9	ns
TPPos4	Transmitter Output Pulse Position for Bit4		8.4	8.8	9.1	ns
TPPos5	Transmitter Output Pulse Position for Bit5		10.6	11.0	11.3	ns
TPPos6	Transmitter Output Pulse Position for Bit6		12.8	13.2	13.5	ns
TCIP	TxCLK IN Period (Figure 10)		15	T	50	ns
TCIH	TxCLK IN High Time (Figure 10)		0.35T	0.5T	0.65T	ns
TCIL	TxCLK IN Low Time (Figure 10)		0.35T	0.5T	0.65T	ns
TSTC	TxIN Setup to TxCLK IN (Figure 10)		2.5			ns
THTC	TxIN Hold to TxCLK IN (Figure 10)		0			ns
TCCD	TxCLK IN to TxCLK OUT Delay @ $25^{\circ}\text{C}$ , $V_{CC}=3.3\text{V}$ (Figure 12)		3	3.7	5.5	ns
TPLLS	Transmitter Phase Lock Loop Set (Figure 14)				10	ms
TPDD	Transmitter Powerdown Delay (Figure 18)				100	ns

(1) The min. and max. are based on the actual bit position of each of the 7 bits within the LVDS data stream across PVT.

(2) The min. and max. limits are based on the worst bit by applying a  $-400\text{ps}/+300\text{ps}$  shift from ideal position.

## Receiver Switching Characteristics

Over recommended operating supply and  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  ranges unless otherwise specified

Symbol	Parameter		Min	Typ	Max	Units
CLHT	CMOS/TTL Low-to-High Transition Time (Figure 7)			2.2	5.0	ns
CHLT	CMOS/TTL High-to-Low Transition Time (Figure 7)			2.2	5.0	ns
RSPos0	Receiver Input Strobe Position for Bit 0 ( <sup>(1)</sup> Figure 21)	f = 40 MHz	1.0	1.4	2.15	ns
RSPos1	Receiver Input Strobe Position for Bit 1		4.5	5.0	5.8	ns
RSPos2	Receiver Input Strobe Position for Bit 2		8.1	8.5	9.15	ns
RSPos3	Receiver Input Strobe Position for Bit 3		11.6	11.9	12.6	ns
RSPos4	Receiver Input Strobe Position for Bit 4		15.1	15.6	16.3	ns
RSPos5	Receiver Input Strobe Position for Bit 5		18.8	19.2	19.9	ns
RSPos6	Receiver Input Strobe Position for Bit 6		22.5	22.9	23.6	ns

(1) The min. and max. are based on the actual bit position of each of the 7 bits within the LVDS data stream across PVT.

## Receiver Switching Characteristics (continued)

Over recommended operating supply and  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$  ranges unless otherwise specified

Symbol	Parameter		Min	Typ	Max	Units
RSPos0	Receiver Input Strobe Position for Bit 0 <sup>(2)</sup> (Figure 21)	f = 66 MHz	0.7	1.1	1.4	ns
RSPos1	Receiver Input Strobe Position for Bit 1		2.9	3.3	3.6	ns
RSPos2	Receiver Input Strobe Position for Bit 2		5.1	5.5	5.8	ns
RSPos3	Receiver Input Strobe Position for Bit 3		7.3	7.7	8.0	ns
RSPos4	Receiver Input Strobe Position for Bit 4		9.5	9.9	10.2	ns
RSPos5	Receiver Input Strobe Position for Bit 5		11.7	12.1	12.4	ns
RSPos6	Receiver Input Strobe Position for Bit 6		13.9	14.3	14.6	ns
RSKM	RxIN Skew Margin <sup>(3)</sup> (Figure 22)	f = 40 MHz	490			ps
		f = 66 MHz	400			ps
RCOP	RxCLK OUT Period (Figure 11)		15	T	50	ns
RCOH	RxCLK OUT High Time (Figure 11)	f = 40 MHz	6.0	10.0		ns
		f = 66 MHz	4.0	6.1		ns
RCOL	RxCLK OUT Low Time (Figure 11)	f = 40 MHz	10.0	13.0		ns
		f = 66 MHz	6.0	7.8		ns
RSRC	RxOUT Setup to RxCLK OUT (Figure 11)	f = 40 MHz	6.5	14.0		ns
		f = 66 MHz	2.5	8.0		ns
RHRC	RxOUT Hold to RxCLK OUT (Figure 11)	f = 40 MHz	6.0	8.0		ns
		f = 66 MHz	2.5	4.0		ns
RCCD	RxCLK IN to RxCLK OUT Delay (Figure 13)	f = 40 MHz	4.0	6.7	8.0	ns
		f = 66 MHz	5.0	6.6	9.0	ns
RPLLS	Receiver Phase Lock Loop Set (Figure 15)				10	ms
RPDD	Receiver Powerdown Delay (Figure 19)				1	$\mu\text{s}$

(2) The min. and max. limits are based on the worst bit by applying a  $-400\text{ps}/+300\text{ps}$  shift from ideal position.

(3) Receiver Skew Margin is defined as the valid data sampling region at the receiver inputs. This margin takes into account the transmitter pulse positions (min and max) and the receiver input setup and hold time (internal data sampling window). This margin allows LVDS interconnect skew, inter-symbol interference (both dependent on type/length of cable), and clock jitter less than 250 ps).

### AC TIMING DIAGRAMS

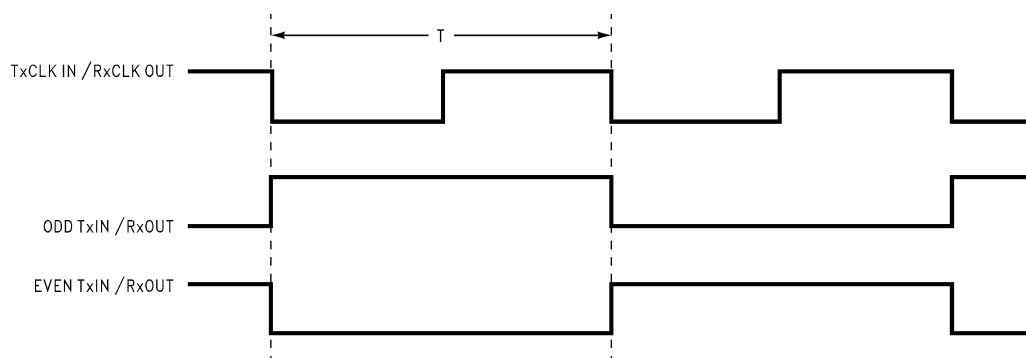
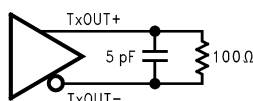
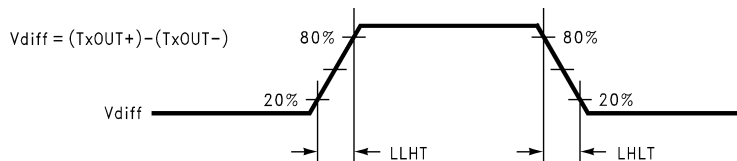
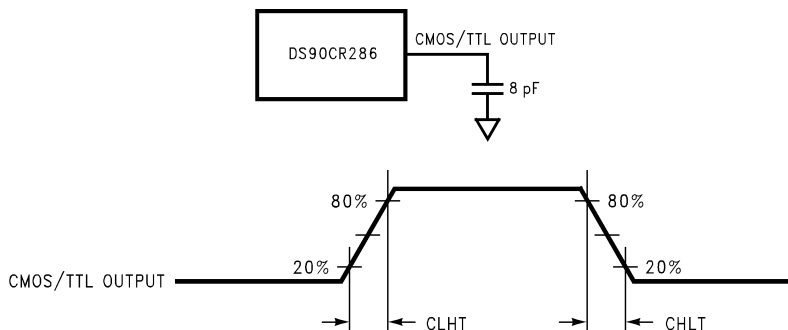


Figure 5. "Worst Case" Test Pattern

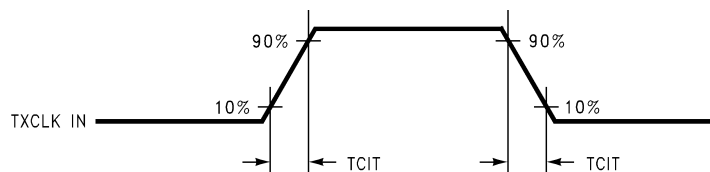




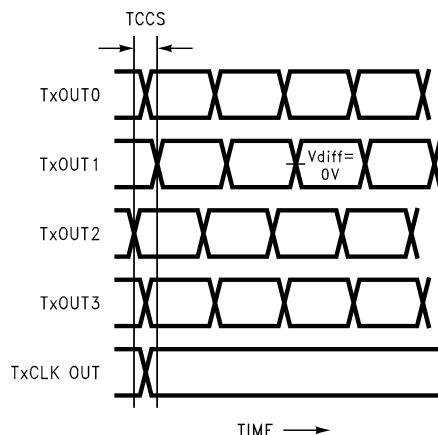
**Figure 6. DS90CR285 (Transmitter) LVDS Output Load and Transition Times**



**Figure 7. DS90CR286 (Receiver) CMOS/TTL Output Load and Transition Times**



**Figure 8. DS90CR285 (Transmitter) Input Clock Transition Time**



- (1) Measurements at  $V_{DIFF} = 0V$
- (2) TCCS measured between earliest and latest LVDS edges.
- (3) TxCLK Differential Low→High Edge

**Figure 9. DS90CR285 (Transmitter) Channel-to-Channel Skew**

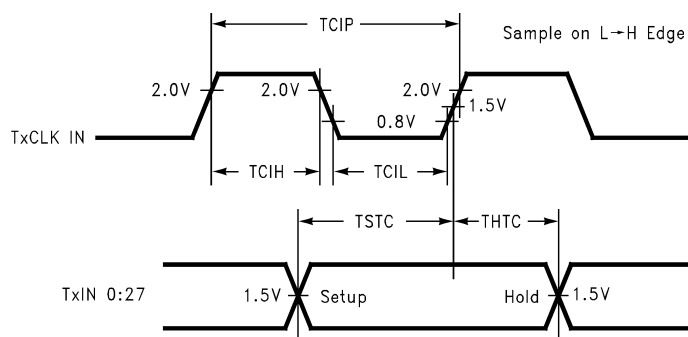


Figure 10. DS90CR285 (Transmitter) Setup/Hold and High/Low Times

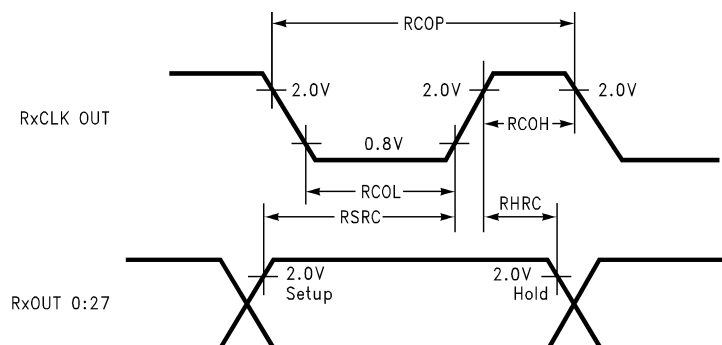


Figure 11. DS90CR286 (Receiver) Setup/Hold and High/Low Times

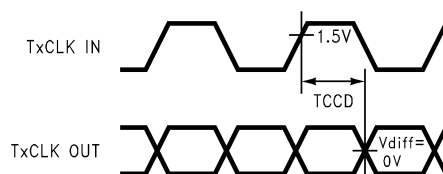


Figure 12. DS90CR285 (Transmitter) Clock In to Clock Out Delay

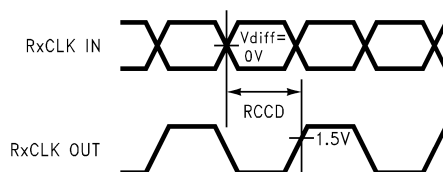
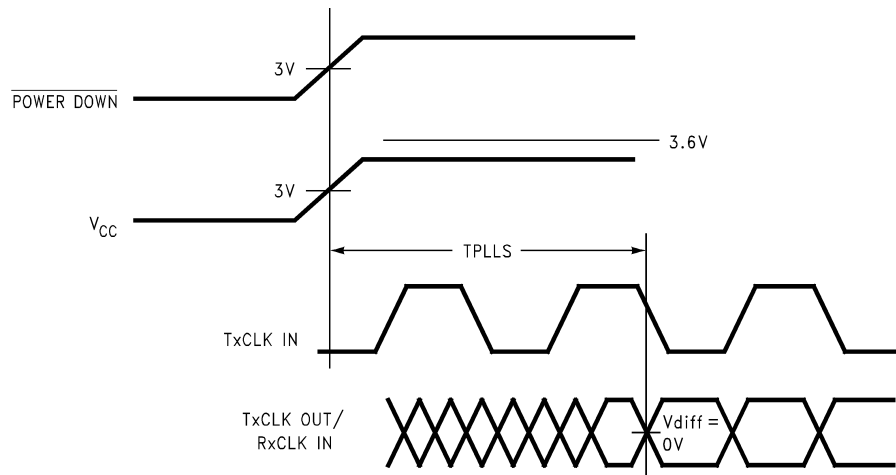
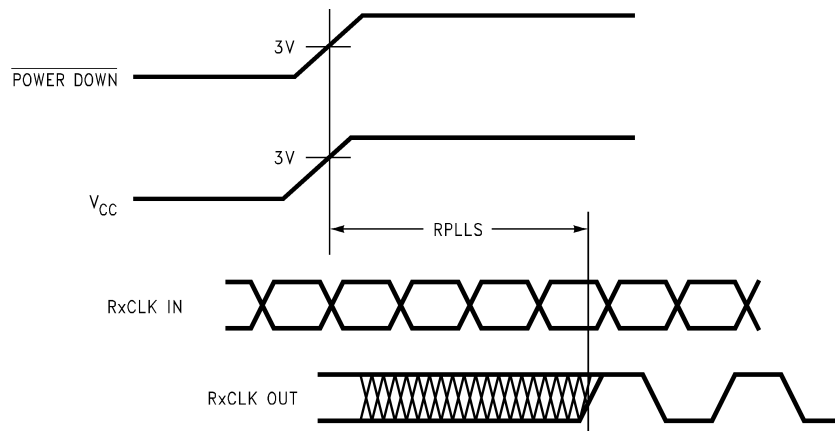


Figure 13. DS90CR286 (Receiver) Clock In to Clock Out Delay

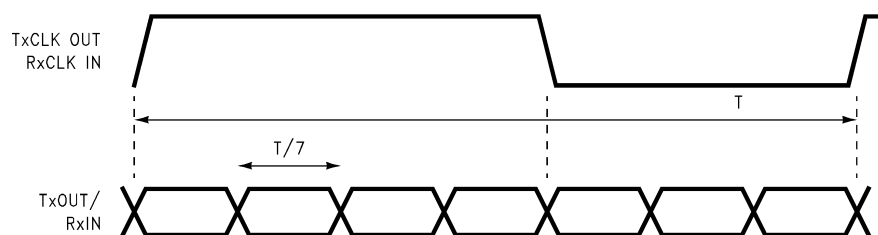




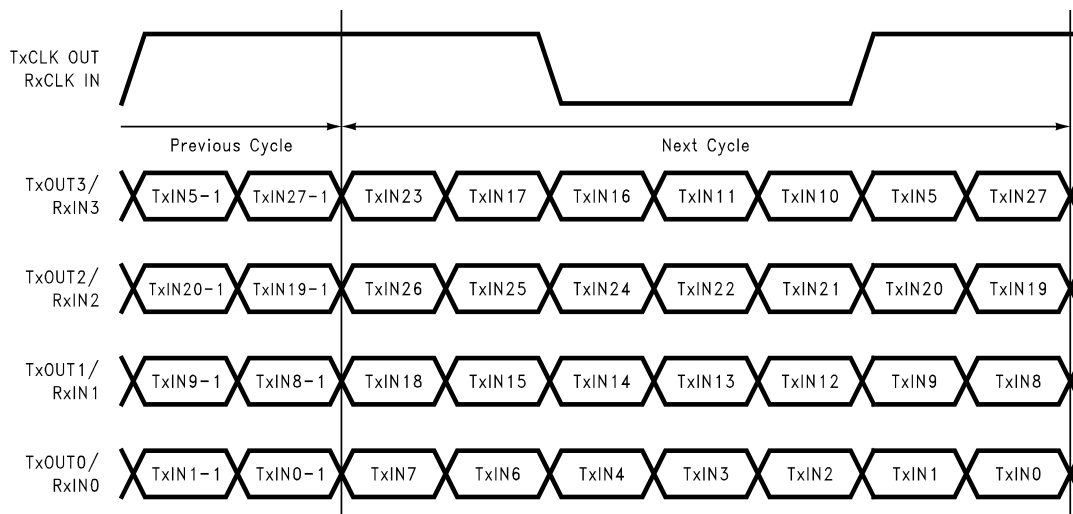
**Figure 14. DS90CR285 (Transmitter) Phase Lock Loop Set Time**



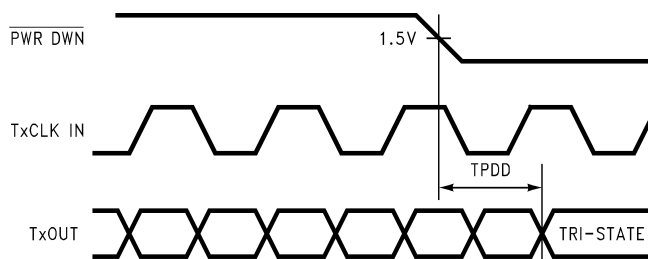
**Figure 15. DS90CR286 (Receiver) Phase Lock Loop Set Time**



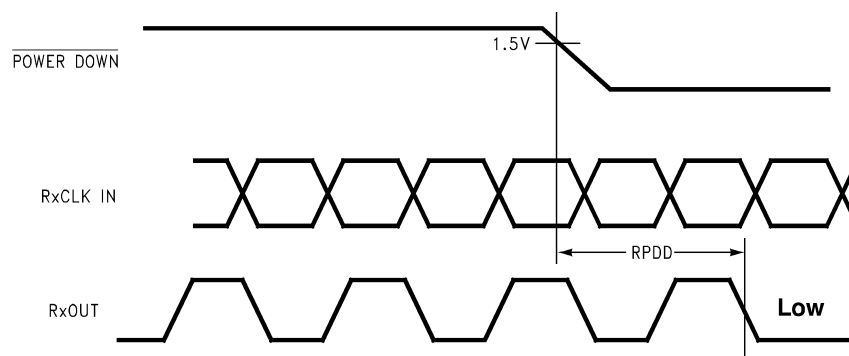
**Figure 16. Seven Bits of LVDS in Once Clock Cycle**



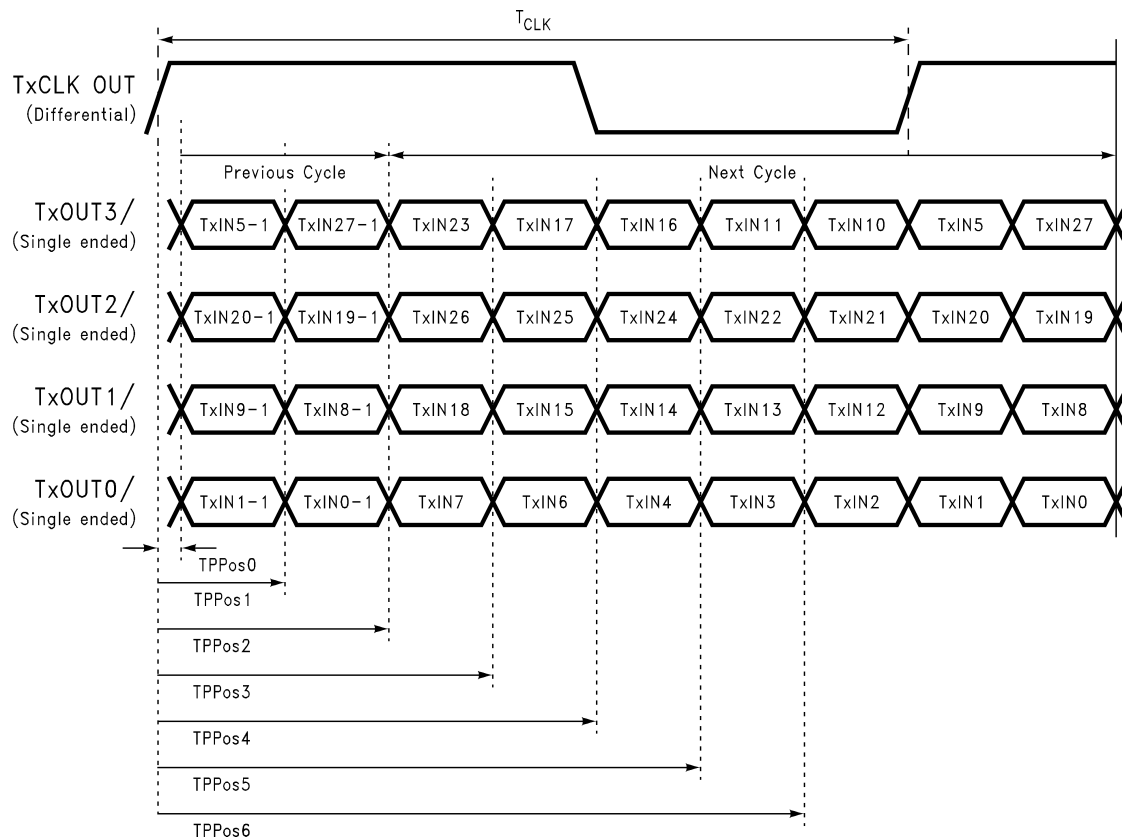
**Figure 17. 28 Parallel TTL Data Inputs Mapped to LVDS Outputs**



**Figure 18. Transmitter Powerdown Delay**



**Figure 19. Receiver Powerdown Delay**



**Figure 20. Transmitter LVDS Output Pulse Position Measurement**

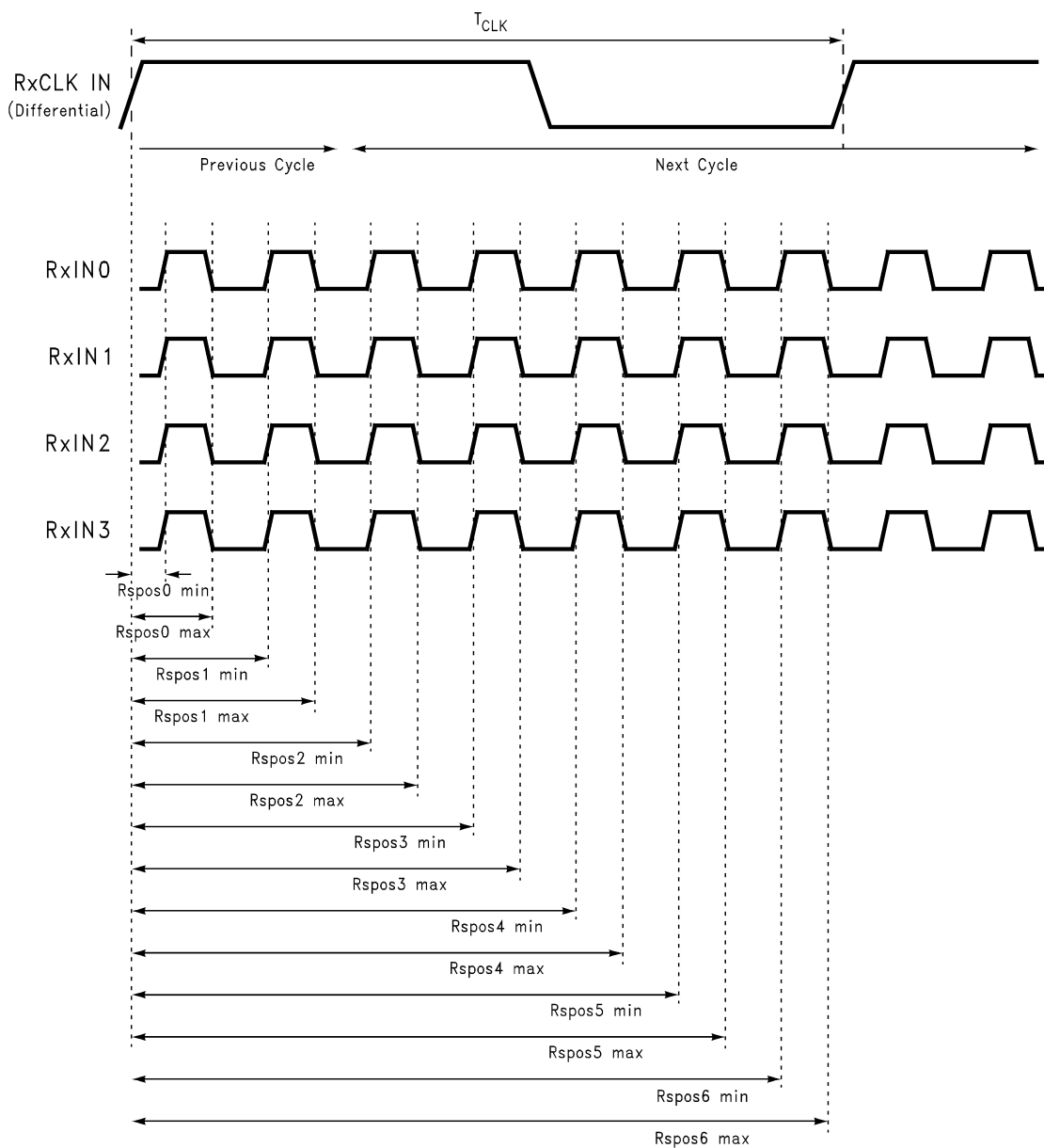
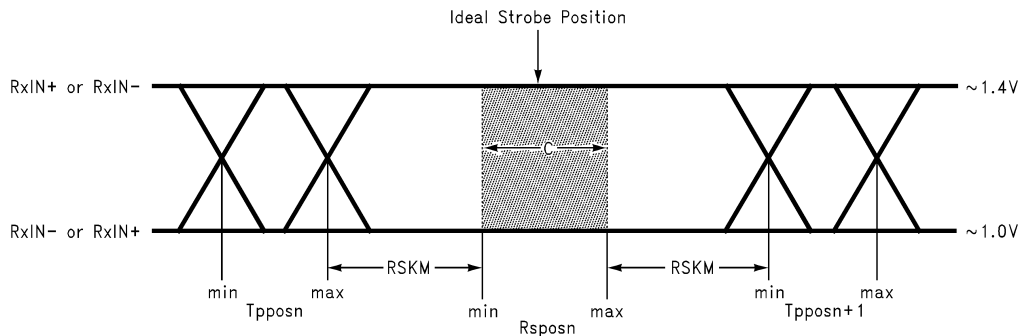


Figure 21. Receiver LVDS Input Strobe Position



C—Setup and Hold Time (Internal data sampling window) defined by Rspn (receiver input strobe position) min and max

Tppos—Transmitter output pulse position (min and max)

$RSKM \geq \text{Cable Skew (type, length)} + \text{Source Clock Jitter (cycle to cycle)} + \text{ISI (Inter-symbol interference)}$

Cable Skew—typically 10 ps–40 ps per foot, media dependent

- (1) Cycle-to-cycle jitter is less than 250 ps
- (2) ISI is dependent on interconnect length; may be zero

**Figure 22. Receiver LVDS Input Skew Margin**

**DS90CR285 DGG (TSSOP) Package Pin Description — Channel Link Transmitter**

Pin Name	I/O	No.	Description
TxIN	I	28	TTL level input.
TxOUT+	O	4	Positive LVDS differential data output.
TxOUT–	O	4	Negative LVDS differential data output.
TxCLK IN	I	1	TTL level clock input. The rising edge acts as data strobe. Pin name TxCLK IN.
TxCLK OUT+	O	1	Positive LVDS differential clock output.
TxCLK OUT–	O	1	Negative LVDS differential clock output.
PWR DWN	I	1	TTL level input. Assertion (low input) TRI-STATES the outputs, ensuring low current at power down.
V <sub>CC</sub>	I	4	Power supply pins for TTL inputs.
GND	I	5	Ground pins for TTL inputs.
PLL V <sub>CC</sub>	I	1	Power supply pin for PLL.
PLL GND	I	2	Ground pins for PLL.
LVDS V <sub>CC</sub>	I	1	Power supply pin for LVDS outputs.
LVDS GND	I	3	Ground pins for LVDS outputs.

**DS90CR286 DGG (TSSOP) Package Pin Description — Channel Link Receiver**

Pin Name	I/O	No.	Description
RxIN+	I	4	Positive LVDS differential data inputs.
RxIN–	I	4	Negative LVDS differential data inputs.
RxOUT	O	28	TTL level data outputs.
RxCLK IN+	I	1	Positive LVDS differential clock input.
RxCLK IN–	I	1	Negative LVDS differential clock input.
RxCLK OUT	O	1	TTL level clock output. The rising edge acts as data strobe. Pin name RxCLK OUT.
PWR DWN	I	1	TTL level input. When asserted (low input) the receiver outputs are low.
V <sub>CC</sub>	I	4	Power supply pins for TTL outputs.
GND	I	5	Ground pins for TTL outputs.
PLL V <sub>CC</sub>	I	1	Power supply for PLL.
PLL GND	I	2	Ground pin for PLL.
LVDS V <sub>CC</sub>	I	1	Power supply pin for LVDS inputs.
LVDS GND	I	3	Ground pins for LVDS inputs.

## APPLICATIONS INFORMATION

The Channel Link devices are intended to be used in a wide variety of data transmission applications. Depending upon the application the interconnecting media may vary. For example, for lower data rate (clock rate) and shorter cable lengths (< 2m), the media electrical performance is less critical. For higher speed/long distance applications the media's performance becomes more critical. Certain cable constructions provide tighter skew (matched electrical length between the conductors and pairs). Twin-coax for example, has been demonstrated at distances as great as 5 meters and with the maximum data transfer of 1.848 Gbit/s. Additional applications information can be found in the following Interface Application Notes:

AN = ####	Topic
AN-1041 ( <a href="#">SNLA218</a> )	Introduction to Channel Link
AN-1108 ( <a href="#">SNLA008</a> )	Channel Link PCB and Interconnect Design-In Guidelines
AN-806 ( <a href="#">SNLA026</a> )	Transmission Line Theory
AN-905 ( <a href="#">SNSNLA035L A008</a> )	Transmission Line Calculations and Differential Impedance
AN-916 ( <a href="#">SNLA219</a> )	Cable Information

## CABLES

A cable interface between the transmitter and receiver needs to support the differential LVDS pairs. The 21-bit CHANNEL LINK chipset (DS90CR215/216) requires four pairs of signal wires and the 28-bit CHANNEL LINK chipset (DS90CR285/286) requires five pairs of signal wires. The ideal cable/connector interface would have a constant 100Ω differential impedance throughout the path. It is also recommended that cable skew remain below 150 ps (@ 66 MHz clock rate) to maintain a sufficient data sampling window at the receiver.

In addition to the four or five cable pairs that carry data and clock, it is recommended to provide at least one additional conductor (or pair) which connects ground between the transmitter and receiver. This low impedance ground provides a common mode return path for the two devices. Some of the more commonly used cable types for point-to-point applications include flat ribbon, flex, twisted pair and Twin-Coax. All are available in a variety of configurations and options. Flat ribbon cable, flex and twisted pair generally perform well in short point-to-point applications while Twin-Coax is good for short and long applications. When using ribbon cable, it is recommended to place a ground line between each differential pair to act as a barrier to noise coupling between adjacent pairs. For Twin-Coax cable applications, it is recommended to utilize a shield on each cable pair. All extended point-to-point applications should also employ an overall shield surrounding all cable pairs regardless of the cable type. This overall shield results in improved transmission parameters such as faster attainable speeds, longer distances between transmitter and receiver and reduced problems associated with EMS or EMI.

The high-speed transport of LVDS signals has been demonstrated on several types of cables with excellent results. However, the best overall performance has been seen when using Twin-Coax cable. Twin-Coax has very low cable skew and EMI due to its construction and double shielding. All of the design considerations discussed here and listed in the supplemental application notes provide the subsystem communications designer with many useful guidelines. It is recommended that the designer assess the tradeoffs of each application thoroughly to arrive at a reliable and economical cable solution.

## BOARD LAYOUT

To obtain the maximum benefit from the noise and EMI reductions of LVDS, attention should be paid to the layout of differential lines. Lines of a differential pair should always be adjacent to eliminate noise interference from other signals and take full advantage of the noise canceling of the differential signals. The board designer should also try to maintain equal length on signal traces for a given differential pair. As with any high speed design, the impedance discontinuities should be limited (reduce the numbers of vias and no 90 degree angles on traces). Any discontinuities which do occur on one signal line should be mirrored in the other line of the differential pair. Care should be taken to ensure that the differential trace impedance match the differential

impedance of the selected physical media (this impedance should also match the value of the termination resistor that is connected across the differential pair at the receiver's input). Finally, the location of the CHANNEL LINK TxOUT/RxIN pins should be as close as possible to the board edge so as to eliminate excessive pcb runs. All of these considerations will limit reflections and crosstalk which adversely effect high frequency performance and EMI.

## UNUSED INPUTS

All unused inputs at the TxIN inputs of the transmitter must be tied to ground. All unused outputs at the RxOUT outputs of the receiver must then be left floating.

## INPUTS

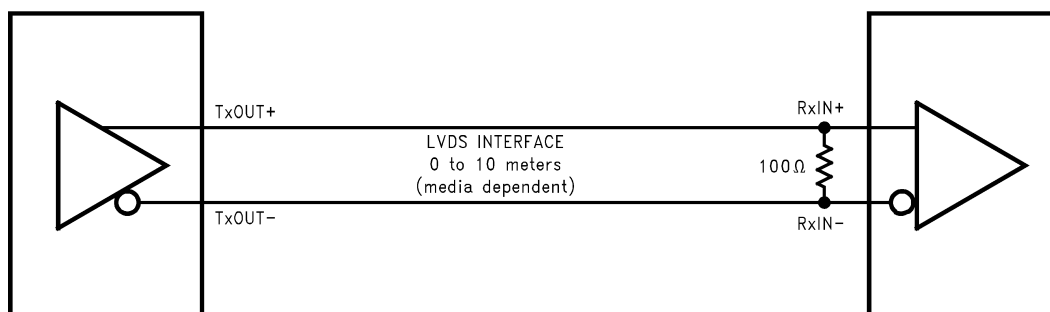
The TxIN and control inputs are compatible with LVCMOS and LVTTTL levels. These pins are not 5V tolerant.

## TERMINATION

Use of current mode drivers requires a terminating resistor across the receiver inputs. The CHANNEL LINK chipset will normally require a single 100Ω resistor between the true and complement lines on each differential pair of the receiver input. The actual value of the termination resistor should be selected to match the differential mode characteristic impedance (90Ω to 120Ω typical) of the cable. [Figure 23](#) shows an example. No additional pull-up or pull-down resistors are necessary as with some other differential technologies such as PECL. Surface mount resistors are recommended to avoid the additional inductance that accompanies leaded resistors. These resistors should be placed as close as possible to the receiver input pins to reduce stubs and effectively terminate the differential lines.

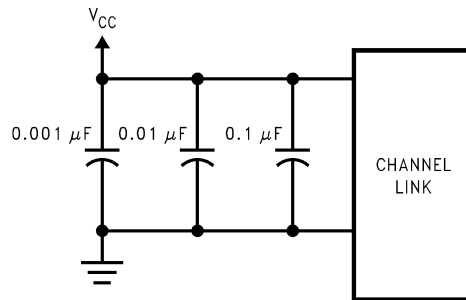
## DECOUPLING CAPACITORS

Bypassing capacitors are needed to reduce the impact of switching noise which could limit performance. For a conservative approach three parallel-connected decoupling capacitors (Multi-Layered Ceramic type in surface mount form factor) between each  $V_{CC}$  and the ground plane(s) are recommended. The three capacitor values are 0.1 μF, 0.01μF and 0.001 μF. An example is shown in [Figure 24](#). The designer should employ wide traces for power and ground and ensure each capacitor has its own via to the ground plane. If board space is limiting the number of bypass capacitors, the PLL  $V_{CC}$  should receive the most filtering/bypassing. Next would be the LVDS  $V_{CC}$  pins and finally the logic  $V_{CC}$  pins.



**Figure 23. LVDS Serialized Link Termination**





**Figure 24. CHANNEL LINK  
Decoupling Configuration**

## CLOCK JITTER

The CHANNEL LINK devices employ a PLL to generate and recover the clock transmitted across the LVDS interface. The width of each bit in the serialized LVDS data stream is one-seventh the clock period. For example, a 66 MHz clock has a period of 15 ns which results in a data bit width of 2.16 ns. Differential skew ( $\Delta t$  within one differential pair), interconnect skew ( $\Delta t$  of one differential pair to another) and clock jitter will all reduce the available window for sampling the LVDS serial data streams. Care must be taken to ensure that the clock input to the transmitter be a clean low noise signal. Individual bypassing of each  $V_{CC}$  to ground will minimize the noise passed on to the PLL, thus creating a low jitter LVDS clock. These measures provide more margin for channel-to-channel skew and interconnect skew as a part of the overall jitter/skew budget.

## COMMON MODE vs. DIFFERENTIAL MODE NOISE MARGIN

The typical signal swing for LVDS is 300 mV centered at +1.2V. The CHANNEL LINK receiver supports a 100 mV threshold therefore providing approximately 200 mV of differential noise margin. Common mode protection is of more importance to the system's operation due to the differential data transmission. LVDS supports an input voltage range of Ground to +2.4V. This allows for a  $\pm 1.0V$  shifting of the center point due to ground potential differences and common mode noise.

## POWER SEQUENCING AND POWERDOWN MODE

Outputs of the CHANNEL LINK transmitter remain in TRI-STATE until the power supply reaches 2V. Clock and data outputs will begin to toggle 10 ms after  $V_{CC}$  has reached 3V and the Powerdown pin is above 1.5V. Either device may be placed into a powerdown mode at any time by asserting the Powerdown pin (active low). Total power dissipation for each device will decrease to 5  $\mu W$  (typical).

The CHANNEL LINK chipset is designed to protect itself from accidental loss of power to either the transmitter or receiver. If power to the transmit board is lost, the receiver clocks (input and output) stop. The data outputs (RxOUT) retain the states they were in when the clocks stopped. When the receiver board loses power, the receiver inputs are shorted to  $V_{CC}$  through an internal diode. Current is limited (5 mA per input) by the fixed current mode drivers, thus avoiding the potential for latchup when powering the device.

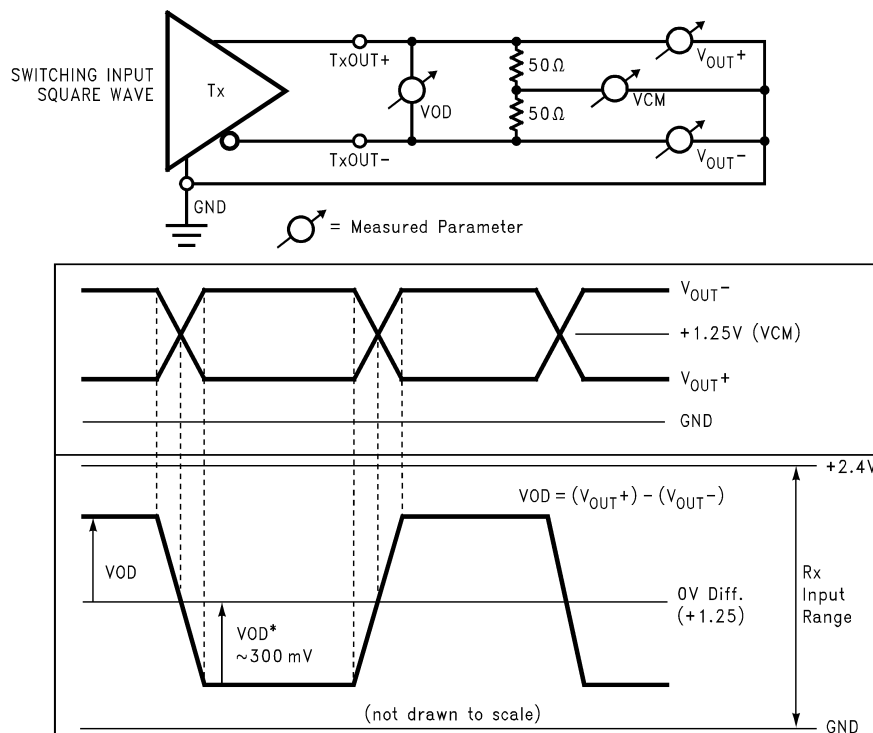


Figure 25. Single-Ended and Differential Waveforms

## REVISION HISTORY

### Changes from Revision B (March 2013) to Revision C

### Page

- Changed layout of National Data Sheet to TI format ..... [18](#)

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
DS90CR285MTD	NRND	TSSOP	DGG	56	34	Non-RoHS & Green	Call TI	Level-2-235C-1 YEAR	-40 to 85	DS90CR285MTD >B	
DS90CR285MTD/NOPB	ACTIVE	TSSOP	DGG	56	34	RoHS & Green	SN	Level-2-260C-1 YEAR	-40 to 85	DS90CR285MTD >B	<a href="#">Samples</a>
DS90CR285MTDX/NOPB	ACTIVE	TSSOP	DGG	56	1000	RoHS & Green	SN	Level-2-260C-1 YEAR	-40 to 85	DS90CR285MTD >B	<a href="#">Samples</a>
DS90CR286MTD	NRND	TSSOP	DGG	56	34	Non-RoHS & Green	Call TI	Level-2-235C-1 YEAR		DS90CR286MTD >B	
DS90CR286MTD/NOPB	NRND	TSSOP	DGG	56	34	RoHS & Green	SN	Level-2-260C-1 YEAR		DS90CR286MTD >B	
DS90CR286MTDX/NOPB	NRND	TSSOP	DGG	56	1000	RoHS & Green	SN	Level-2-260C-1 YEAR		DS90CR286MTD >B	

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## TAPE AND REEL INFORMATION



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS90CR285MTDX/NOPB	TSSOP	DGG	56	1000	330.0	24.4	8.6	14.5	1.8	12.0	24.0	Q1
DS90CR286MTDX/NOPB	TSSOP	DGG	56	1000	330.0	24.4	8.6	14.5	1.8	12.0	24.0	Q1

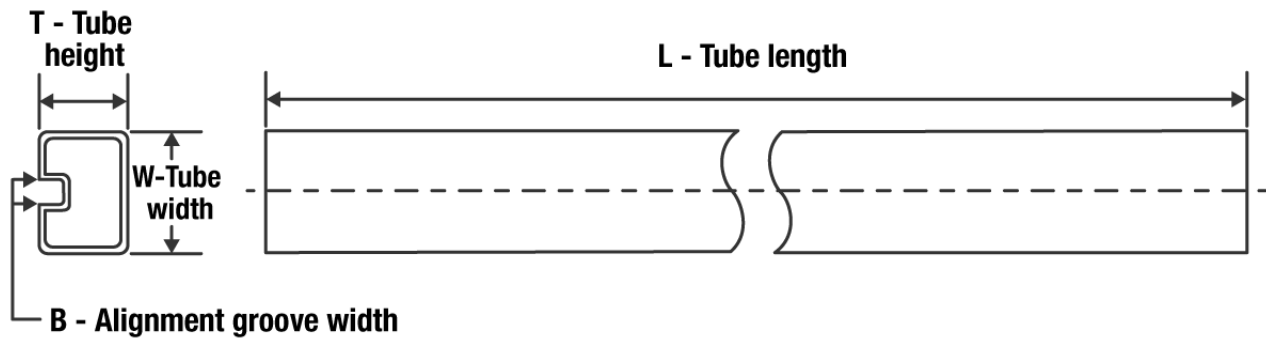
## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS90CR285MTDX/NOPB	TSSOP	DGG	56	1000	367.0	367.0	45.0
DS90CR286MTDX/NOPB	TSSOP	DGG	56	1000	367.0	367.0	45.0

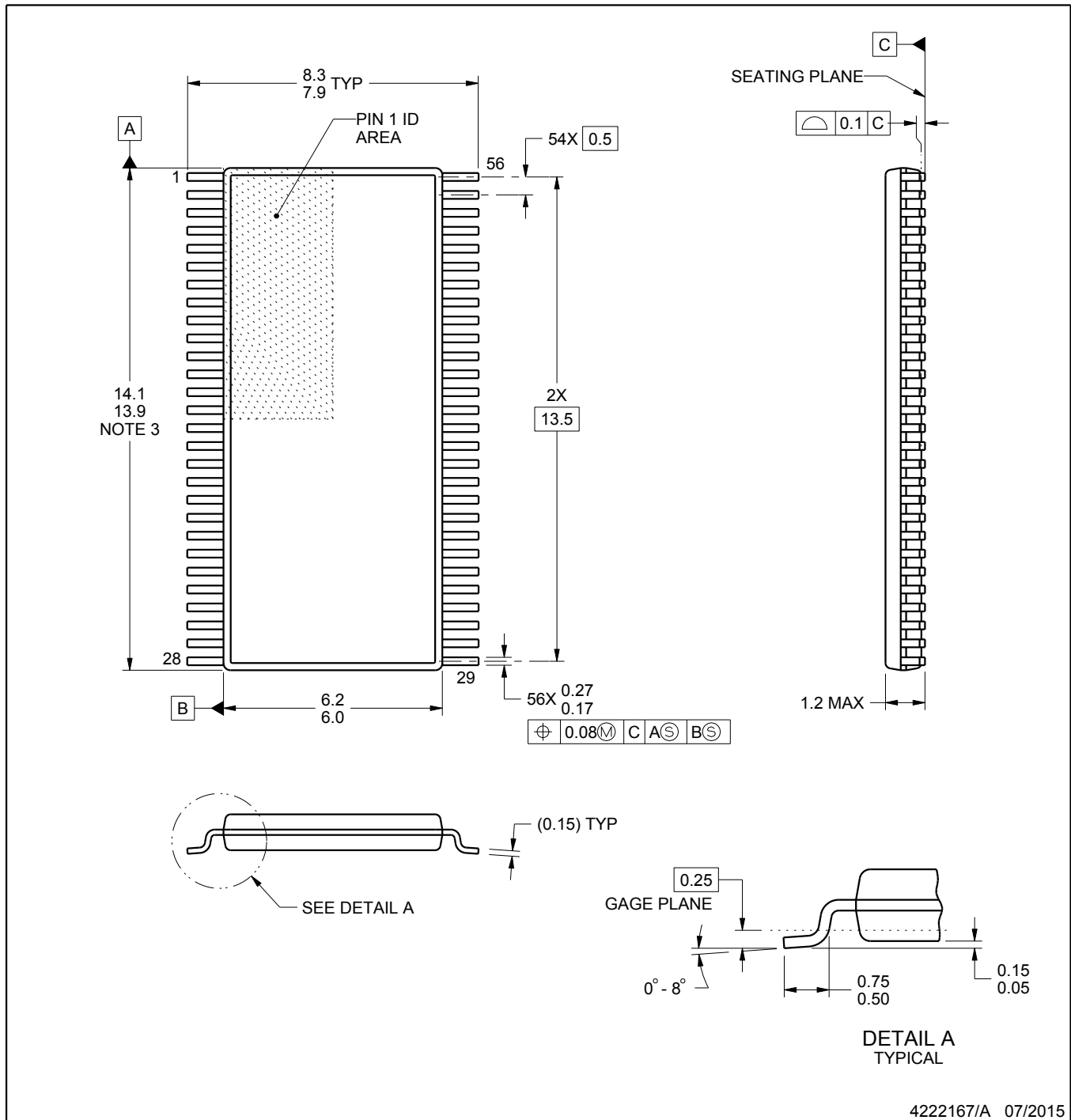
## TUBE



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
DS90CR285MTD	DGG	TSSOP	56	34	495	10	2540	5.79
DS90CR285MTD	DGG	TSSOP	56	34	495	10	2540	5.79
DS90CR285MTD/NOPB	DGG	TSSOP	56	34	495	10	2540	5.79
DS90CR286MTD	DGG	TSSOP	56	34	495	10	2540	5.79
DS90CR286MTD	DGG	TSSOP	56	34	495	10	2540	5.79
DS90CR286MTD/NOPB	DGG	TSSOP	56	34	495	10	2540	5.79





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## NOTES:

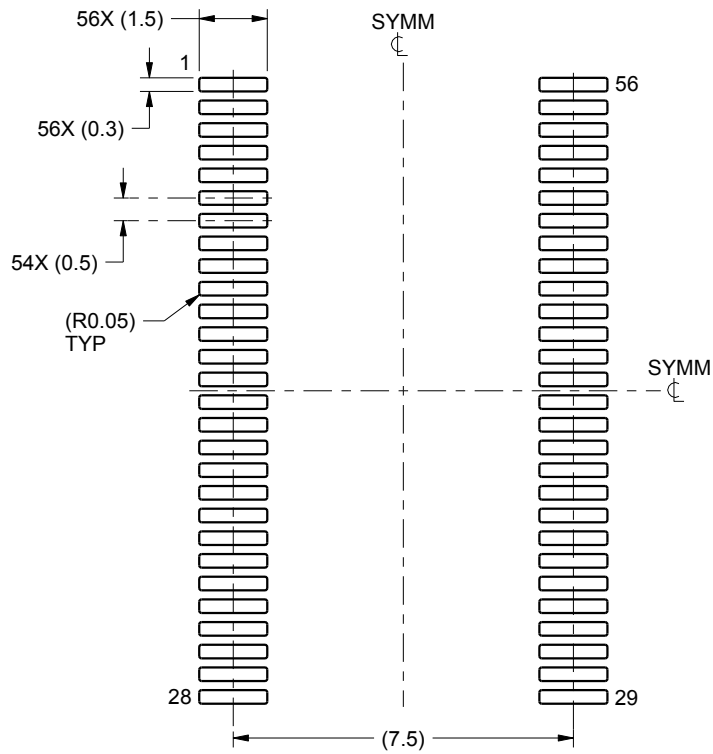
- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- Reference JEDEC registration MO-153.

# EXAMPLE BOARD LAYOUT

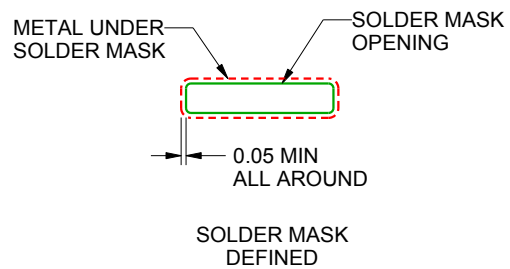
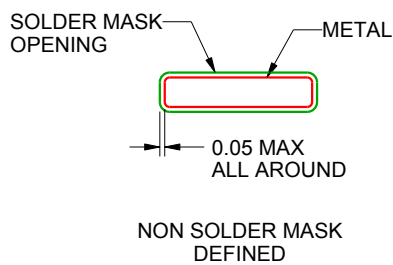
DGG0056A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE  
SCALE:6X



SOLDER MASK DETAILS

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NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

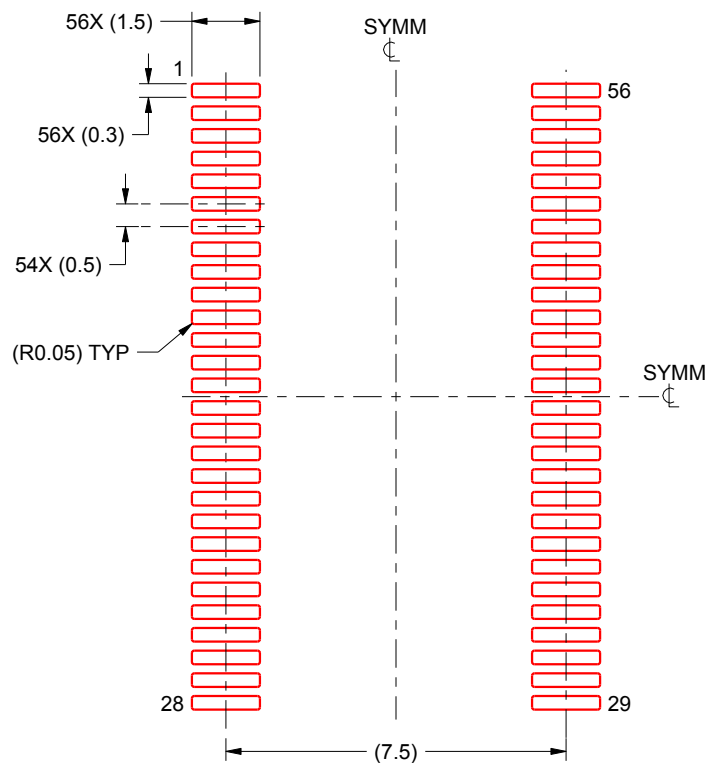
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

DGG0056A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:6X

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NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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